

Total No. of Questions : 6]

SEAT No. :

P552

[Total No. of Pages : 2

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**F.E. (Common) (Semester - II)**

**APPLIED SCIENCE - II**

**Physics**

**(2008 Course)**

*Time : 2 Hours]*

*[Max. Marks : 50*

*Instructions to the candidates:*

- 1) *Neat diagrams must be drawn wherever necessary.*
- 2) *Figures to the right indicate full marks.*
- 3) *You are advised to attempt not more than questions.*
- 4) *Use of logarithmic tables Slide rule, Mollier charts, electronic pocket calculator and steam tables is allowed.*
- 5) *Assume suitable data, if necessary.*

Constants:

$$h = 6.63 \times 10^{-34} \text{ J.s}$$

$$e = 1.6 \times 10^{-19} \text{ C}$$

$$m_e = 9.1 \times 10^{-31} \text{ kg}$$

$$C = 3 \times 10^8 \text{ m/s}$$

- Q1)** a) Explain de-Broglie's hypothesis of matter waves and obtain an equation for wavelength of matter waves in terms of K.E. of particle. [7]
- b) Deduce Schrodinger's time independent wave equation. [6]
- c) An electron is trapped in a rigid box of length  $2\text{Å}$ . Compute first two energy eigen values of electron in eV. [4]

OR

- Q2)** a) Derive an equation of energy and wave function when a particle is trapped in rigid box. [7]
- b) State and explain Heisenberg's uncertainty principle. [6]
- c) Calculate de-Broglie wavelength of an electron accelerated through potential difference of 1000V. [4]

**P.T.O.**

- Q3)** a) Explain construction and working of Ruby Laser. [6]  
b) What is superconductivity? Explain BCS theory of superconductors. [6]  
c) State and explain: [4]  
i) Meissner effect.  
ii) Critical field.

OR

- Q4)** a) Explain construction and working of He-Ne Laser. [6]  
b) Distinguish between Type I and Type II superconductors. [6]  
c) State any four applications of Laser. [4]

- Q5)** a) What is Fermi function? Show that Fermi level lies at the centre of V.B. and C.B. in case of an intrinsic semiconductor. [7]  
b) Explain synthesis of metal nano-particles by colloidal route. [6]  
c) If the mobility of electrons is  $1000 \text{ cm}^2/\text{V.s}$  and the resistivity of N-type semiconductor to be formed is  $10^{-6} \Omega\text{cm}$ , calculate the number of donor atoms to be added. [4]

OR

- Q6)** a) State and explain Hall effect. What is Hall coefficient? State applications of Hall effect. [7]  
b) Explain any two properties of nanoparticles. [6]  
c) Draw energy band diagrams for a P-N junction diode in forward biased and reverse biased condition. [4]

